

# SHANGHAI SUNRISE ELECTRONICS CO., LTD.

## S2A THRU S2M

SURFACE MOUNT GLASS PASSIVATED RECTIFIER

TECHNICAL SPECIFICATION

VOLTAGE: 50 TO 1000V CURRENT: 2.0A

#### **FEATURES**

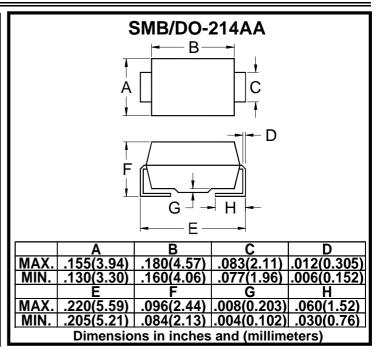
- Ideal for surface mount pick and place application
- Low profile package
- Built-in strain relief
- High surge capability
- High temperature soldering guaranteed: 260°C/10sec/at terminal

#### MECHANICAL DATA

 Terminal: Plated leads solderable per MIL-STD 202E, method 208C

 Case: Molded with UL-94 Class V-O recognized flame retardant epoxy

• Polarity: Color band denotes cathode



### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

(Single-phase, half-wave, 60Hz, resistive or inductive load rating at 25°C, unless otherwise stated, for capacitive load, derate current by 20%)

RATINGS	SYMBOL	S2A	S2B	S2D	S2G	S2J	S2K	S2M	UNITS
Maximum Repetitive Peak Reverse Voltage	$V_{RRM}$	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	$V_{RMS}$	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	$V_{DC}$	50	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Current		2.0							Α
(T <sub>L</sub> =110°C)	I <sub>F(AV)</sub>								
Peak Forward Surge Current (8.3ms single	1	60							Α
half sine-wave superimposed on rated load)	I <sub>FSM</sub>								A
Maximum Instantaneous Forward Voltage	$V_{F}$	1.1							V
(at rated forward current)	٧F								
Maximum DC Reverse Current T <sub>a</sub> =25°	°C ,	5.0							μΑ
(at rated DC blocking voltage) T <sub>a</sub> =125°	C I <sub>R</sub>	200							μΑ
Typical Junction Capacitance (Note	1) C <sub>J</sub>	C <sub>J</sub> 30							pF
Typical Thermal Resistance (Note	2) R <sub>θ</sub> (ja)	16							°C/W
Storage and Operation Junction Temperature	$T_{STG},T_{J}$	-65 to +150						°C	
Noto:	·	•	•	•		•	•		

Note:

- 1.Measured at 1.0 MHz and applied voltage of 4.0V<sub>dc</sub>
- 2. Thermal resistance from junction to terminal mounted on 5×5mm copper pad area